

CTVS – Ceramic transient voltage suppressors

SMD multilayer varistors (MLVs),
surge protection series

Series/Type:

Date: April 2016

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Multilayer varistors (MLVs)

Surge protection series

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EPCOS type designation system for surge protection series

| CT | 1206 | K | 30 | E2 | G | K2 |
|--|------|---|----|----|---|----|
| <p>Construction: CT \triangleq Single chip with nickel barrier termination (AgNiSn) CN \triangleq Single chip with silver-platin termination (AgPt)</p> | | | | | | |
| <p>Case sizes: 0805 1206 1210 1812 2220</p> | | | | | | |
| <p>Tolerance of the varistor voltage: K \triangleq $\pm 10\%$, standard S \triangleq Special tolerance</p> | | | | | | |
| <p>Maximum RMS operating voltage (V_{RMS}): 30 \triangleq 30 V</p> | | | | | | |
| <p>Features: E2 \triangleq Increased energy handling capability TELE \triangleq Specified for 10/700 μs pulses, acc. to telecom standards A \triangleq Special tolerance</p> | | | | | | |
| <p>Taping mode: G \triangleq 180-mm reel, 7" G2 \triangleq 330-mm reel, 13"</p> | | | | | | |
| <p>Termination: K2 \triangleq Code for AgPt termination (CN types only)</p> | | | | | | |

Multilayer varistors (MLVs)

Surge protection series

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Description

The surge protection series comprises a range of multilayer varistors for protection against severe transient overvoltage and high surge currents, such as 8/20 μ s pulses with peak currents up to 6000 A and 10/700 μ s pulses up to 45 A.

Features

- High energy absorption capability
- High surge load capability acc. to IEC 61000-4-5
- Reliable ESD protection up to 30 kV acc. to IEC 61000-4-2, level 4
- High surge voltage capability up to 2 kV for 10/700 μ s acc. to IEC 61000-4-5 (types with $V_{RMS,max} \leq 60$ V)
- Bidirectional protection
- Low leakage current
- Long-term ESD stability
- RoHS-compatible, lead-free
- PSpice simulation models available

Applications

- Industrial applications
- Building safety and security applications
- Power supplies
- Control and measurement equipment
- Hard disk drives

Design

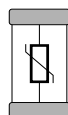
- Multilayer technology
- Flammability rating better than UL 94 V-0
- Termination (see "Soldering directions"):
 - CT types with nickel barrier terminations (AgNiSn), recommended for lead-free soldering, and compatible with tin/lead solder
 - CN types with silver-platin termination (AgPt) for reflow and wave soldering with solder on tin/lead basis or lead-free with a silver containing solder

V/I characteristics and derating curves

V/I and derating curves are attached to the data sheet. The curves are sorted by V_{RMS} and then by case size, which is included in the type designation.

Single chip

Internal circuit



MLV0006-H

Available case sizes:

| EIA | Metric |
|------|--------|
| 0805 | 2012 |
| 1206 | 3216 |
| 1210 | 3225 |
| 1812 | 4532 |
| 2220 | 5750 |

Multilayer varistors (MLVs)

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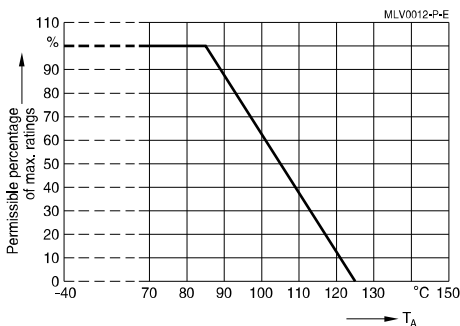
General technical data

| | | | | |
|-------------------------------|--------------------------------|-----------------|-------------|----|
| Maximum RMS operating voltage | | $V_{RMS,max}$ | 30 ... 115 | V |
| Maximum DC operating voltage | | $V_{DC,max}$ | 38 ... 150 | V |
| Maximum surge current | (8/20 μ s) | $I_{surge,max}$ | 40 ... 6000 | A |
| Maximum surge current | (10/700 μ s) | $I_{surge,max}$ | 45 | A |
| Maximum clamping voltage | | $V_{clamp,max}$ | 77 ... 360 | V |
| Operating temperature | (8/20 μ s surge ratings) | T_{op} | -55/+125 | °C |
| Operating temperature | (10/700 μ s surge ratings) | T_{op} | -40/+85 | °C |
| Storage temperature | (8/20 μ s surge ratings) | LCT/UCT | -55/+150 | °C |
| Storage temperature | (10/700 μ s surge ratings) | LCT/UCT | -40/+125 | °C |
| Response time | | t_{resp} | < 0.5 | ns |

Temperature derating

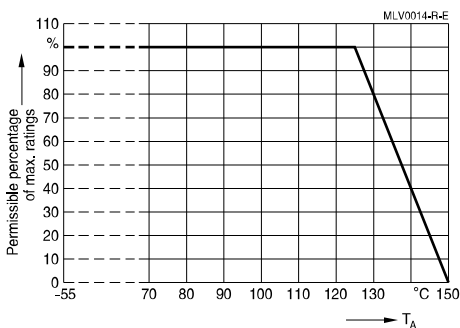
Climatic category:

-40/+85 °C for chip size 1812 (dedicated telecom types: CT1812S60AG2, CT1812K75TELEG2, CT1812S95 AG2, CT1812K115TELEG2)



Climatic category:

-55/+125 °C for chip sizes 0805, 1206, 1210, 1812, and 2220



Multilayer varistors (MLVs)
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Electrical specifications and ordering codes
Maximum ratings ($T_{op,max}$)

| Type | Ordering code | $V_{RMS,max}$ | $V_{DC,max}$ | $I_{surge,max}$ (8/20 μ s) | $I_{surge,max}$ (10/700 μ s) | W_{max} (2 ms) | $P_{diss,max}$ (2 ms) |
|--|-----------------|---------------|--------------|-----------------------------------|-------------------------------------|---------------------|--------------------------|
| | | V | V | A | A | mJ | mW |
| High surge protection types, 8/20 μs surge rating, $T_{op,max} = +125$ °C | | | | | | | |
| CT2220K30E2G | B72540T6300K062 | 30 | 38 | 5000 | - | 15000 | 20 |
| CN2220K30E2GK2 | B72542V6300K062 | 30 | 38 | 6000 | - | 15000 | 20 |
| CN2220K50E2GK2 | B72542V6500K062 | 50 | 65 | 4500 | - | 15000 | 20 |
| CT2220K50E2G | B72540T6500K062 | 50 | 65 | 4500 | - | 15000 | 20 |
| CT2220S50E3G | B72540T6500S162 | 50 | 63 | 4500 | - | 15000 | 20 |
| Surge protection types, 8/20 μs surge rating, $T_{op,max} = +125$ °C | | | | | | | |
| CT0805K30G | B72510T0300K062 | 30 | 38 | 80 | - | 300 | 5 |
| CT1206K30G | B72520T0300K062 | 30 | 38 | 200 | - | 1100 | 8 |
| CT1210K30G | B72530T0300K062 | 30 | 38 | 300 | - | 2000 | 10 |
| CT1812K30G | B72580T0300K062 | 30 | 38 | 800 | - | 4200 | 15 |
| CT2220K30G | B72540T0300K062 | 30 | 38 | 1200 | - | 12000 | 20 |
| CT0805K35G | B72510T0350K062 | 35 | 45 | 80 | - | 300 | 5 |
| CT1206K35G | B72520T0350K062 | 35 | 45 | 100 | - | 400 | 8 |
| CT1210K35G | B72530T0350K062 | 35 | 45 | 250 | - | 2000 | 10 |
| CT1812K35G | B72580T0350K062 | 35 | 45 | 500 | - | 4000 | 15 |
| CT1206K40G | B72520T0400K062 | 40 | 56 | 100 | - | 500 | 8 |
| CT1210K40G | B72530T0400K062 | 40 | 56 | 250 | - | 2300 | 10 |
| CT1812K40G | B72580T0400K062 | 40 | 56 | 500 | - | 4800 | 15 |
| CT2220K40G | B72540T0400K062 | 40 | 56 | 1000 | - | 9000 | 20 |
| CT1206K50G | B72520T0500K062 | 50 | 65 | 100 | - | 600 | 8 |
| CT1210K50G | B72530T0500K062 | 50 | 65 | 200 | - | 1600 | 10 |
| CT1812K50G | B72580T0500K062 | 50 | 65 | 400 | - | 4500 | 15 |
| CT2220K50G | B72540T0500K062 | 50 | 65 | 800 | - | 5600 | 20 |
| CT1206K60G | B72520T0600K062 | 60 | 85 | 100 | - | 700 | 8 |
| CT1210K60G | B72530T0600K062 | 60 | 85 | 200 | - | 2000 | 10 |
| CT1812K60G | B72580T0600K062 | 60 | 85 | 400 | - | 5800 | 15 |
| CT2220K60G | B72540T0600K062 | 60 | 85 | 800 | - | 6800 | 20 |
| CT1812K130G2 | B72580T0131K072 | 130 | 170 | 250 | - | 3500 | 15 |
| Telecom types, 10/700 μs surge rating, $T_{op,max} = +85$ °C | | | | | | | |
| CT1812S60AG2 | B72580T0600S172 | 60 | 85 | 400 | 45 | 2200 | 15 |
| CT1812K75TELEG2 | B72580T6750K072 | 75 | 100 | 400 | 45 | 2500 | 15 |
| CT1812S95AG2 | B72580T0950S172 | 95 | 125 | 250 | 45 | 2800 | 15 |
| CT1812K115TELEG2 | B72580T6111K072 | 115 | 150 | 250 | 45 | 3200 | 15 |

Multilayer varistors (MLVs)
Surge protection series
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Characteristics (T_A = 25 °C)

| Type | V _V (1 mA) V | ΔV _V % | V _{clamp,max} V | I _{clamp} (8/20 μs) A | C _{typ} ⁽¹⁾ (1 MHz, 1 V) pF |
|--|-------------------------------|----------------------|-----------------------------|--------------------------------------|---|
| High surge protection types, 8/20 μs surge rating, T_{op,max} = +125 °C | | | | | |
| CT2220K30E2G | 47 | ±10 | 77 | 10 | 10000 |
| CN2220K30E2GK2 | 47 | ±10 | 77 | 10 | 10000 |
| CN2220K50E2GK2 | 82 | ±10 | 135 | 10 | 3000 |
| CT2220K50E2G | 82 | ±10 | 135 | 10 | 3000 |
| CT2220S50E3G | 77.5 | ±8.4 | 115 | 10 | 8800 |
| Surge protection types, 8/20 μs surge rating, T_{op,max} = +125 °C | | | | | |
| CT0805K30G | 47 | ±10 | 77 | 1 | 200 |
| CT1206K30G | 47 | ±10 | 77 | 1 | 500 |
| CT1210K30G | 47 | ±10 | 77 | 2.5 | 1000 |
| CT1812K30G | 47 | ±10 | 77 | 5 | 2000 |
| CT2220K30G | 47 | ±10 | 77 | 10 | 4000 |
| CT0805K35G | 56 | ±10 | 95 | 1 | 150 |
| CT1206K35G | 56 | ±10 | 90 | 1 | 200 |
| CT1210K35G | 56 | ±10 | 90 | 2.5 | 600 |
| CT1812K35G | 56 | ±10 | 90 | 5 | 1200 |
| CT1206K40G | 68 | ±10 | 110 | 1 | 250 |
| CT1210K40G | 68 | ±10 | 110 | 2.5 | 500 |
| CT1812K40G | 68 | ±10 | 110 | 5 | 1000 |
| CT2220K40G | 68 | ±10 | 110 | 10 | 2000 |
| CT1206K50G | 82 | ±10 | 135 | 1 | 120 |
| CT1210K50G | 82 | ±10 | 135 | 2.5 | 250 |
| CT1812K50G | 82 | ±10 | 135 | 5 | 500 |
| CT2220K50G | 82 | ±10 | 135 | 10 | 1000 |
| CT1206K60G | 100 | ±10 | 165 | 1 | 100 |
| CT1210K60G | 100 | ±10 | 165 | 2.5 | 200 |
| CT1812K60G | 100 | ±10 | 165 | 5 | 400 |
| CT2220K60G | 100 | ±10 | 165 | 10 | 800 |
| CT1812K130G2 | 205 | ±10 | 340 | 5 | 200 |
| Telecom types, 10/700 μs surge rating, T_{op,max} = +85 °C | | | | | |
| CT1812S60AG2 | 100 | +19/-1 | 200 | 45 | 400 |
| CT1812K75TELEG2 | 120 | ±10 | 250 | 45 | 320 |
| CT1812S95AG2 | 165 | ±10 | 270 | 45 | 250 |
| CT1812K115TELEG2 | 180 | ±10 | 360 | 45 | 200 |

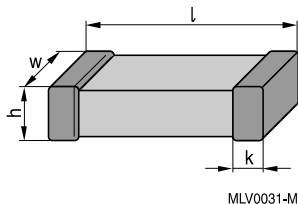
1) Measurement frequency: f = 1 MHz for C < 100 pF, f = 1 kHz for C ≥ 100 pF

Multilayer varistors (MLVs)

Surge protection series

SMD

Dimensional drawing



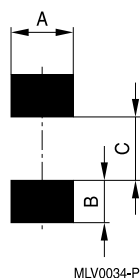
Dimensions in mm

| Case size EIA / mm | l | w | h | k |
|-----------------------|-----------|------------|---------------------------|---------------|
| 0201 / 0603 | 0.6 ±0.03 | 0.30 ±0.03 | 0.33 max. | 0.15 ±0.05 |
| 0402 / 1005 | 1.0 ±0.15 | 0.50 ±0.10 | 0.6 max. | 0.10 ... 0.30 |
| 0603 / 1608 | 1.6 ±0.15 | 0.80 ±0.10 | 0.9 max. | 0.10 ... 0.40 |
| 0805 / 2012 | 2.0 ±0.20 | 1.25 ±0.15 | 1.4 max. | 0.13 ... 0.75 |
| 1206 / 3216 | 3.2 ±0.30 | 1.60 ±0.20 | 1.7 max. | 0.25 ... 0.75 |
| 1210 / 3225 | 3.2 ±0.30 | 2.50 ±0.25 | 1.7 max. | 0.25 ... 0.75 |
| 1812 / 4532 | 4.5 ±0.40 | 3.20 ±0.30 | 2.5 max. | 0.25 ... 1.00 |
| 2220 / 5750 | 5.7 ±0.40 | 5.00 ±0.40 | 2.5 max. ^{1) 2)} | 0.25 ... 1.00 |

1) $h_{\max} = 3.0$ mm for type CN2220K30E2GK2, CN2220K50E2GK2, CT2220K30E2G and CT2220K50E2G

2) $h_{\max} = 3.3$ mm for type CT2220S50E3G

Recommended solder pad layout



Dimensions in mm

| Case size EIA / mm | A | B | C |
|-----------------------|------|------|------|
| 0201 / 0603 | 0.30 | 0.25 | 0.30 |
| 0402 / 1005 | 0.60 | 0.60 | 0.50 |
| 0603 / 1608 | 1.00 | 1.00 | 1.00 |
| 0805 / 2012 | 1.40 | 1.20 | 1.00 |
| 1206 / 3216 | 1.80 | 1.20 | 2.10 |
| 1210 / 3225 | 2.80 | 1.20 | 2.10 |
| 1812 / 4532 | 3.60 | 1.50 | 3.00 |
| 2220 / 5750 | 5.50 | 1.50 | 4.20 |

Multilayer varistors (MLVs)
Surge protection series
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Delivery mode

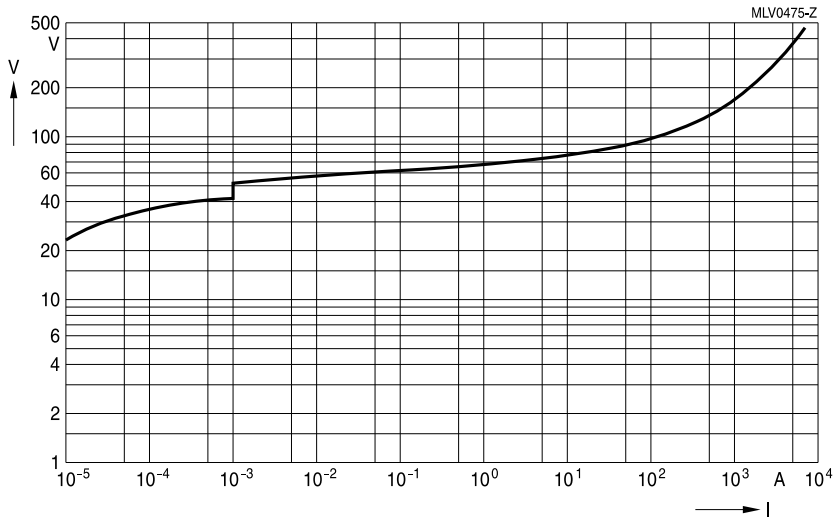
| EIA case size | Taping | Reel size mm | Packing unit pcs. | Type | Ordering code |
|--------------------|---------|-----------------|----------------------|------------------|-----------------|
| Single chip | | | | | |
| 0805 | Blister | 180 | 3000 | CT0805K30G | B72510T0300K062 |
| 0805 | Blister | 180 | 3000 | CT0805K35G | B72510T0350K062 |
| 1206 | Blister | 180 | 2000 | CT1206K30G | B72520T0300K062 |
| 1206 | Blister | 180 | 2000 | CT1206K35G | B72520T0350K062 |
| 1206 | Blister | 180 | 2000 | CT1206K40G | B72520T0400K062 |
| 1206 | Blister | 180 | 2000 | CT1206K50G | B72520T0500K062 |
| 1206 | Blister | 180 | 2000 | CT1206K60G | B72520T0600K062 |
| 1210 | Blister | 180 | 2000 | CT1210K30G | B72530T0300K062 |
| 1210 | Blister | 180 | 2000 | CT1210K35G | B72530T0350K062 |
| 1210 | Blister | 180 | 2000 | CT1210K40G | B72530T0400K062 |
| 1210 | Blister | 180 | 2000 | CT1210K50G | B72530T0500K062 |
| 1210 | Blister | 180 | 2000 | CT1210K60G | B72530T0600K062 |
| 1812 | Blister | 180 | 1000 | CT1812K30G | B72580T0300K062 |
| 1812 | Blister | 180 | 1000 | CT1812K35G | B72580T0350K062 |
| 1812 | Blister | 180 | 1000 | CT1812K40G | B72580T0400K062 |
| 1812 | Blister | 180 | 1000 | CT1812K50G | B72580T0500K062 |
| 1812 | Blister | 180 | 1000 | CT1812K60G | B72580T0600K062 |
| 1812 | Blister | 180 | 3000 | CT1812K130G2 | B72580T0131K072 |
| 1812 | Blister | 330 | 3000 | CT1812K115TELEG2 | B72580T6111K072 |
| 1812 | Blister | 330 | 3000 | CT1812S95AG2 | B72580T0950S172 |
| 1812 | Blister | 330 | 4000 | CT1812K75TELEG2 | B72580T6750K072 |
| 1812 | Blister | 330 | 4000 | CT1812S60AG2 | B72580T0600S172 |
| 2220 | Blister | 180 | 500 | CT2220S50E3G | B72540T6500S162 |
| 2220 | Blister | 180 | 600 | CN2220K30E2GK2 | B72542V6300K062 |
| 2220 | Blister | 180 | 600 | CN2220K50E2GK2 | B72542V6500K062 |
| 2220 | Blister | 180 | 600 | CT2220K30E2G | B72540T6300K062 |
| 2220 | Blister | 180 | 600 | CT2220K50E2G | B72540T6500K062 |
| 2220 | Blister | 180 | 1000 | CT2220K30G | B72540T0300K062 |
| 2220 | Blister | 180 | 1000 | CT2220K40G | B72540T0400K062 |
| 2220 | Blister | 180 | 1000 | CT2220K50G | B72540T0500K062 |
| 2220 | Blister | 180 | 1000 | CT2220K60G | B72540T0600K062 |

Multilayer varistors (MLVs)

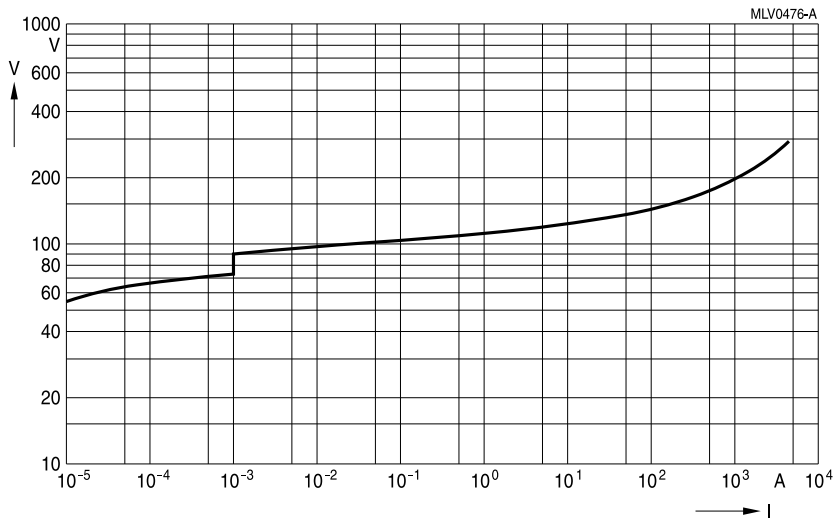
Surge protection series

SMD

V/I characteristics for high surge protection types



CN2220K30E2GK2



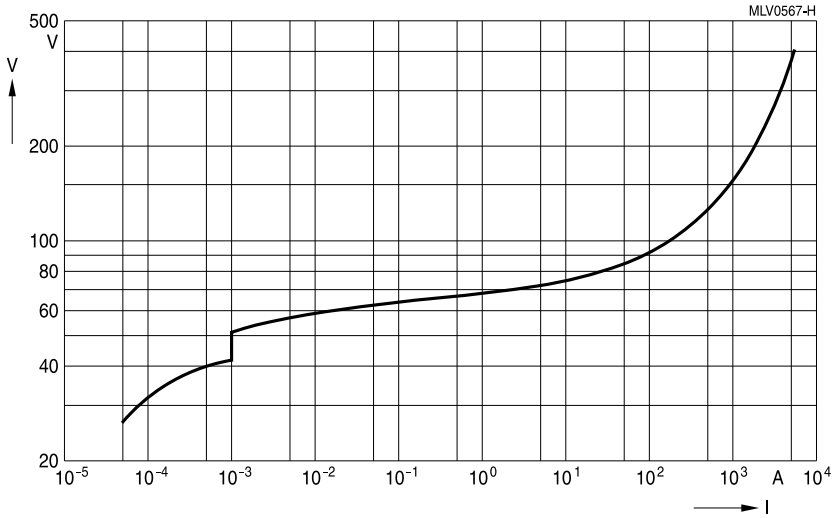
CN2220K50E2GK2

Multilayer varistors (MLVs)

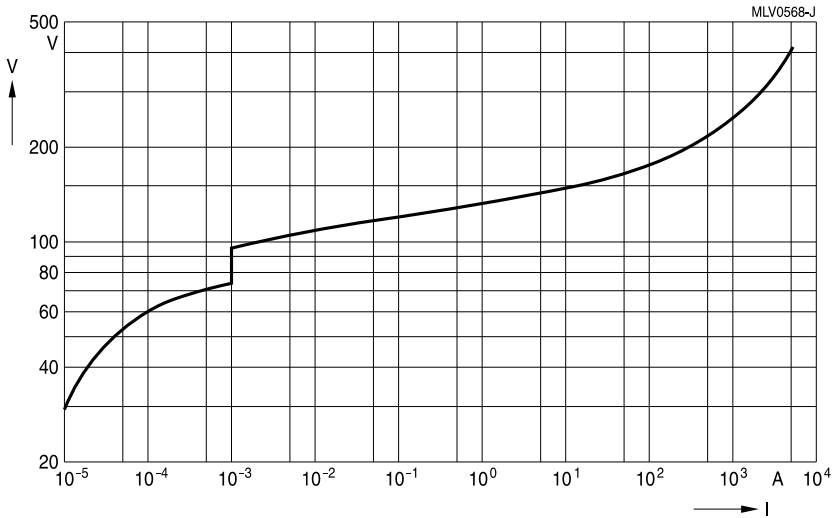
Surge protection series

SMD

V/I characteristics for high surge protection types



CT2220K30E2G



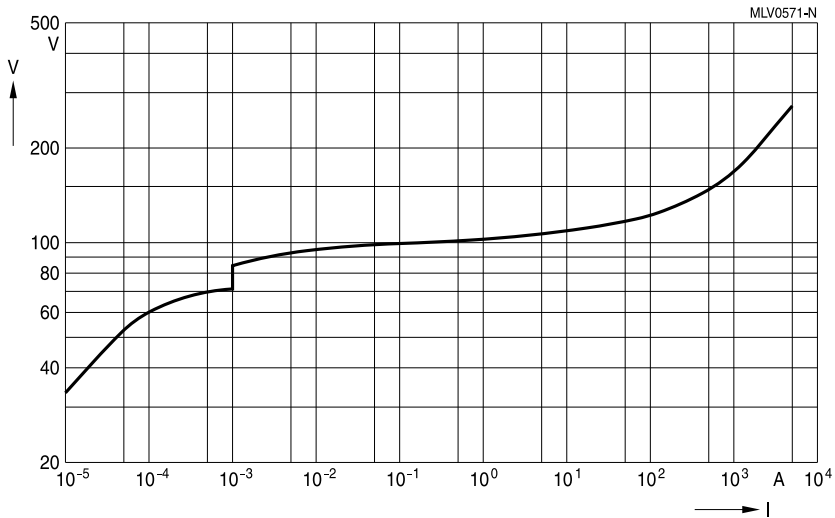
CT2220K50E2G

Multilayer varistors (MLVs)

Surge protection series

SMD

V/I characteristics for high surge protection types



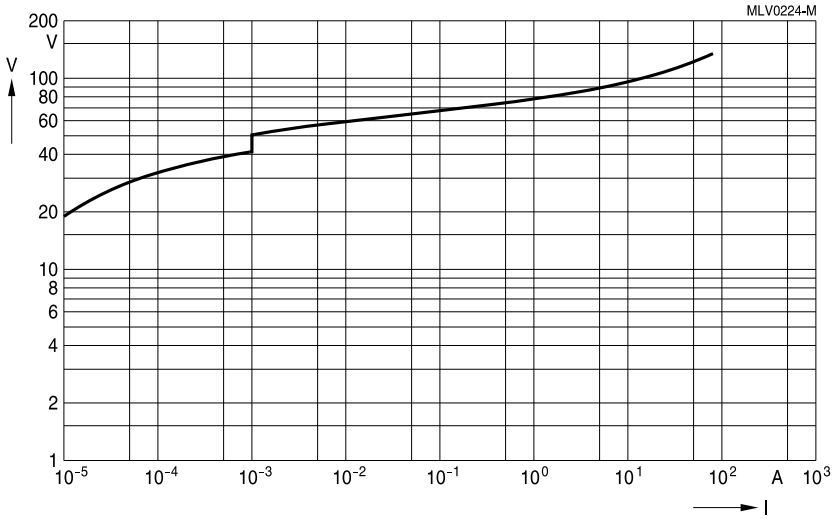
CT2220S50E3G

Multilayer varistors (MLVs)

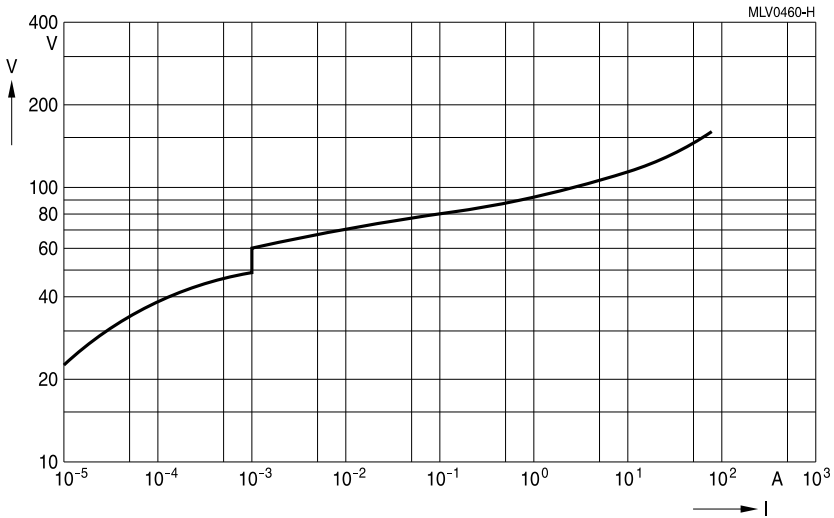
Surge protection series

SMD

V/I characteristics for surge protection types



CT0805K30G



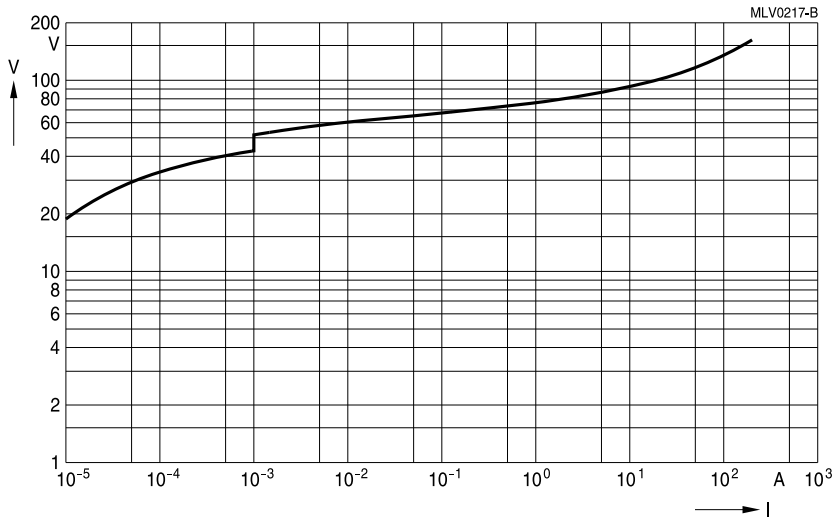
CT0805K35G

Multilayer varistors (MLVs)

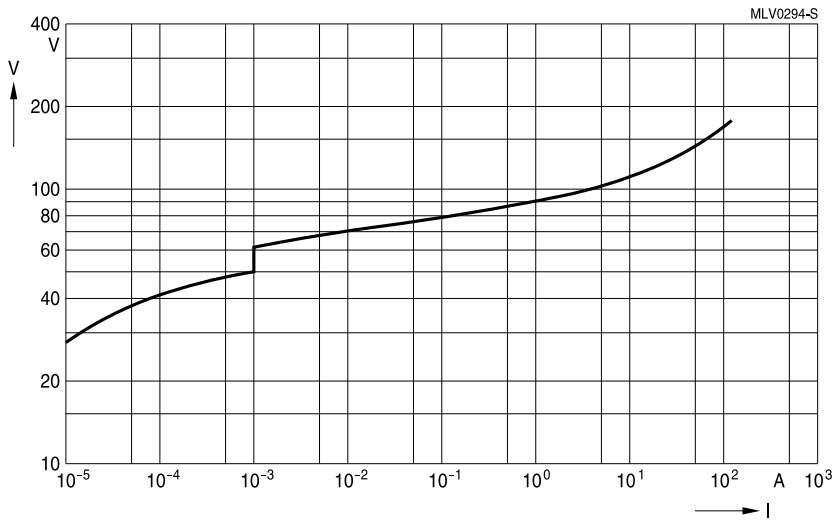
Surge protection series

SMD

V/I characteristics for surge protection types



CT1206K30G



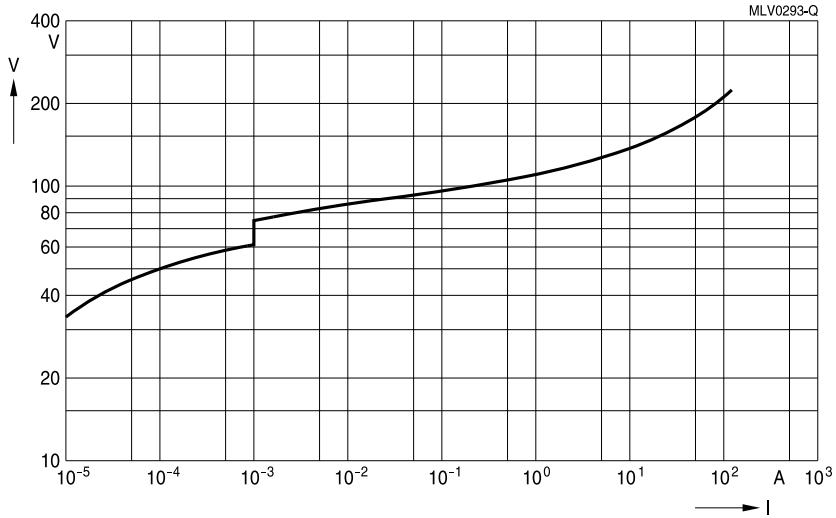
CT1206K35G

Multilayer varistors (MLVs)

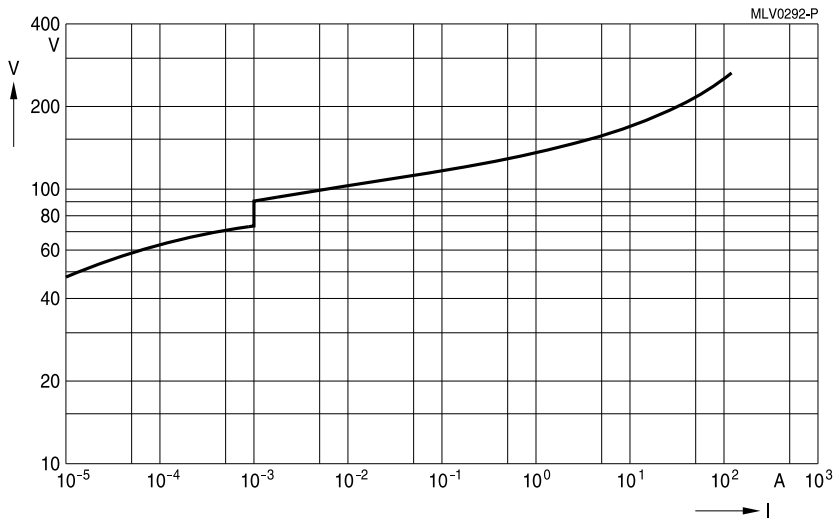
Surge protection series

SMD

V/I characteristics for surge protection types



CT1206K40G



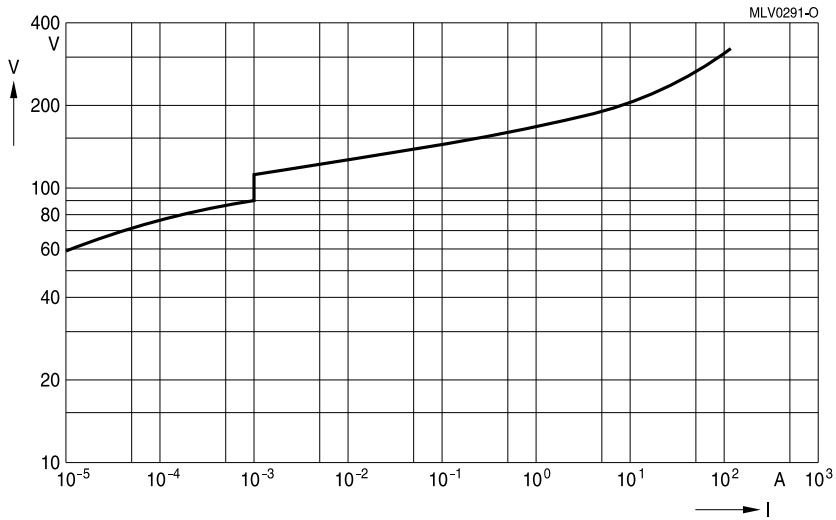
CT1206K50G

Multilayer varistors (MLVs)

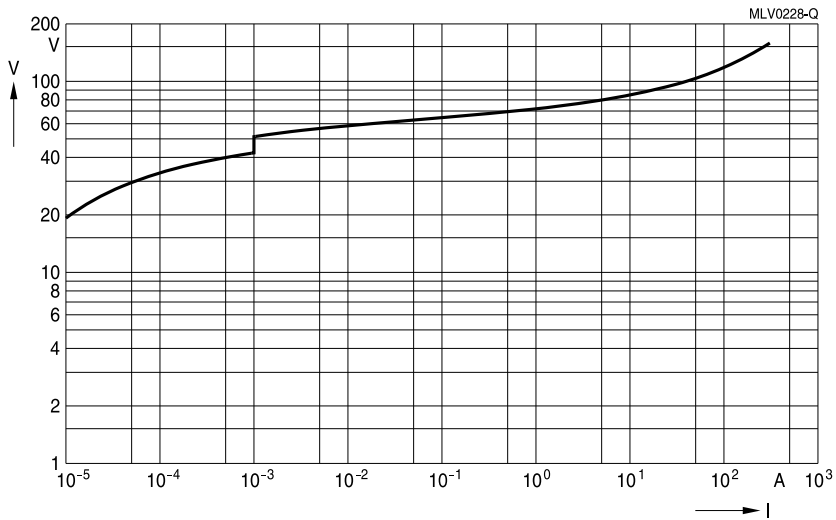
Surge protection series

SMD

V/I characteristics for surge protection types



CT1206K60G



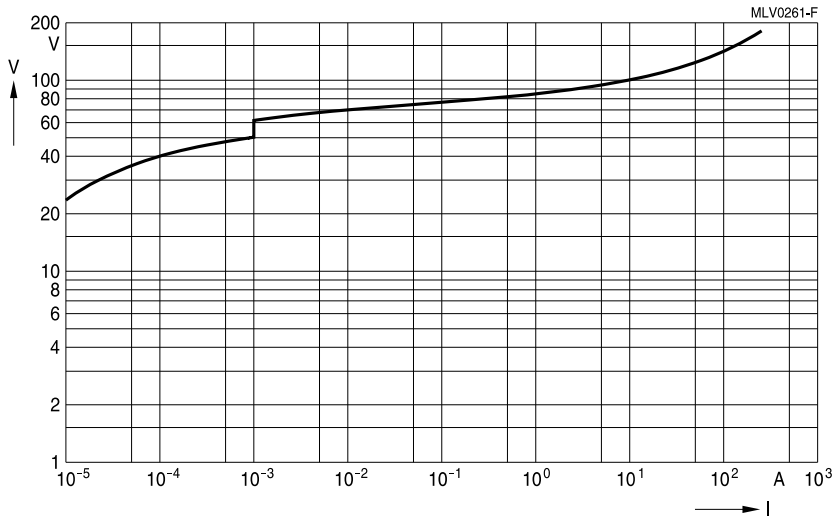
CT1210K30G

Multilayer varistors (MLVs)

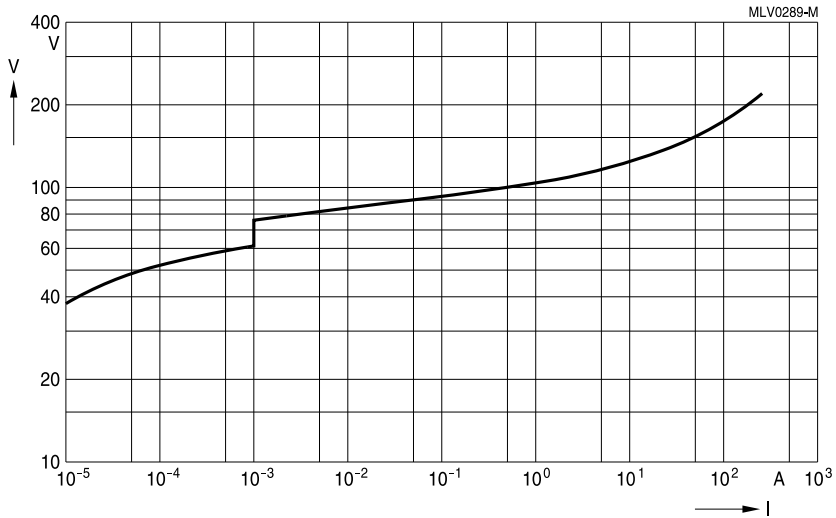
Surge protection series

SMD

V/I characteristics for surge protection types



CT1210K35G



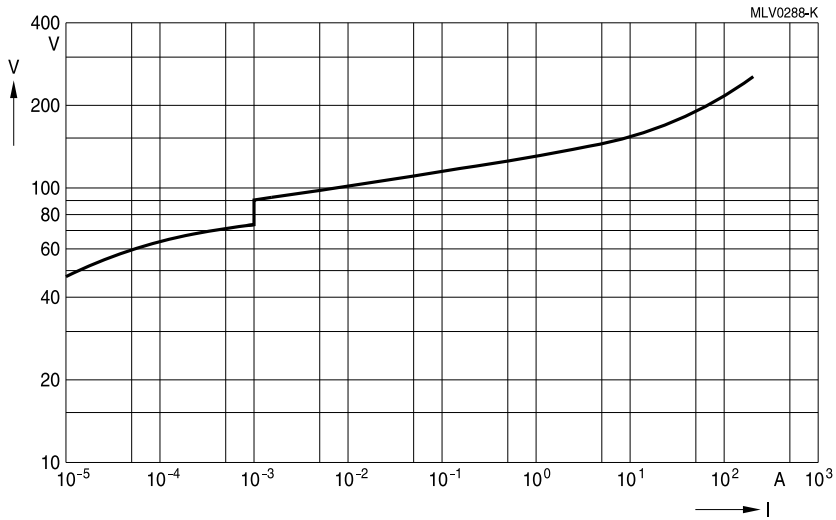
CT1210K40G

Multilayer varistors (MLVs)

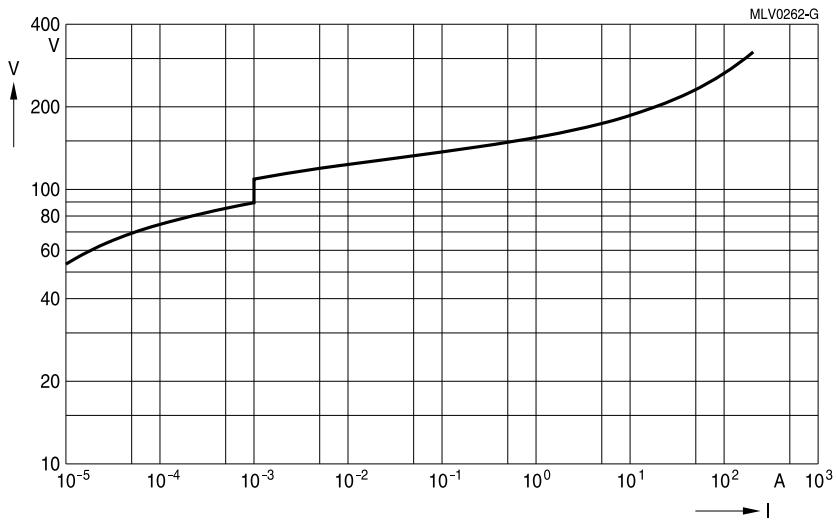
Surge protection series

SMD

V/I characteristics for surge protection types



CT1210K50G



CT1210K60G

Multilayer varistors (MLVs)

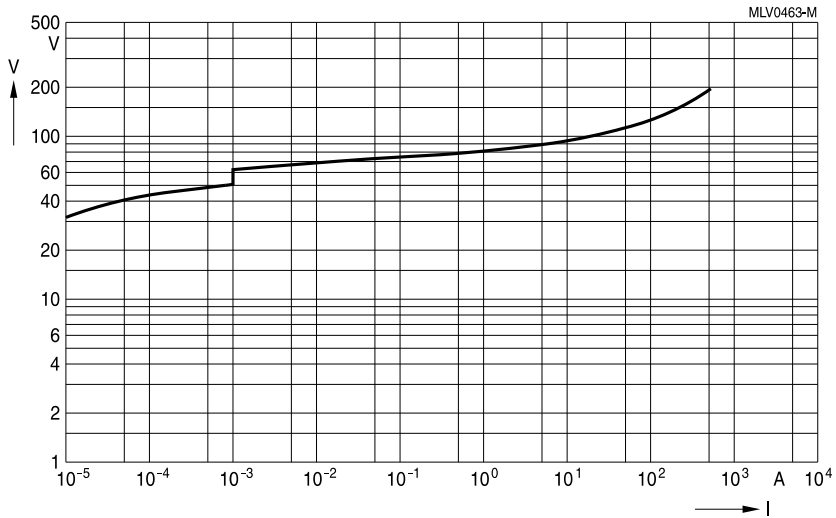
Surge protection series

SMD

V/I characteristics for surge protection types



CT1812K30G



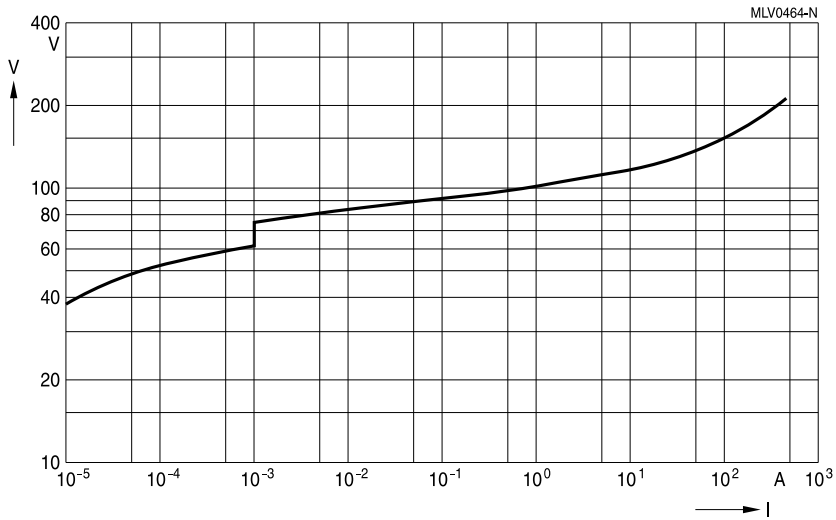
CT1812K35G

Multilayer varistors (MLVs)

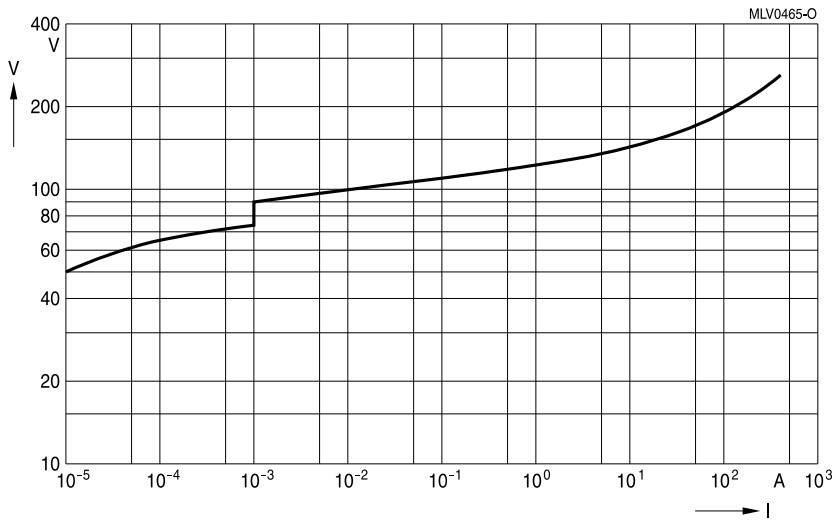
Surge protection series

SMD

V/I characteristics for surge protection types



CT1812K40G



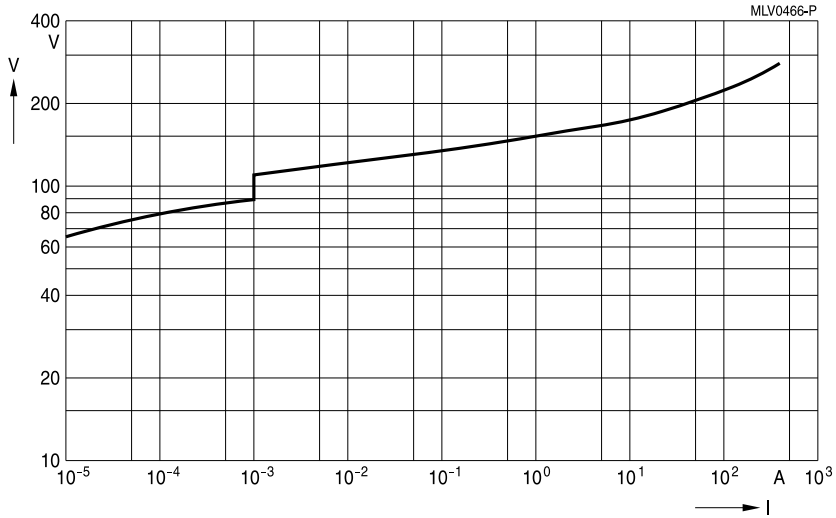
CT1812K50G

Multilayer varistors (MLVs)

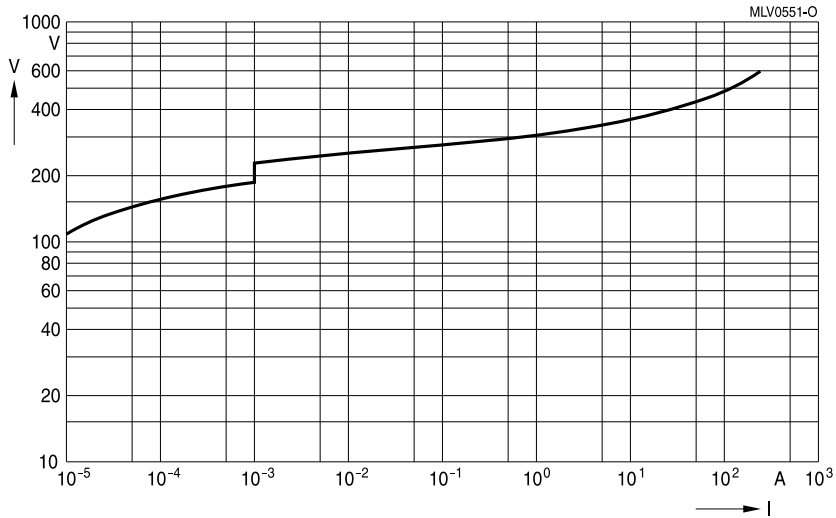
Surge protection series

SMD

V/I characteristics for surge protection types



CT1812K60G



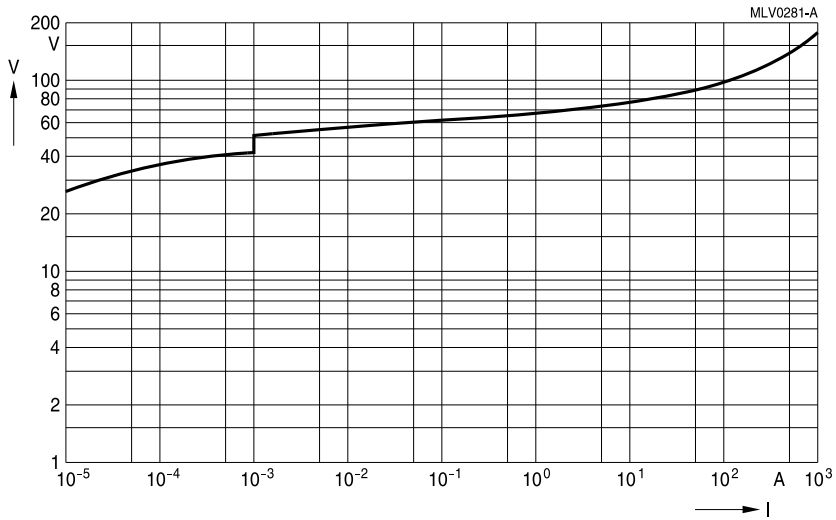
CT1812K130G2

Multilayer varistors (MLVs)

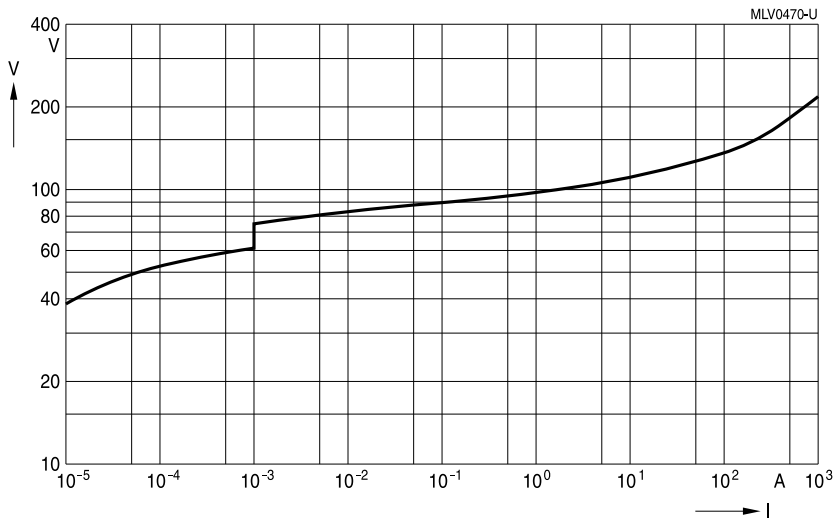
Surge protection series

SMD

V/I characteristics for surge protection types



CT2220K30G



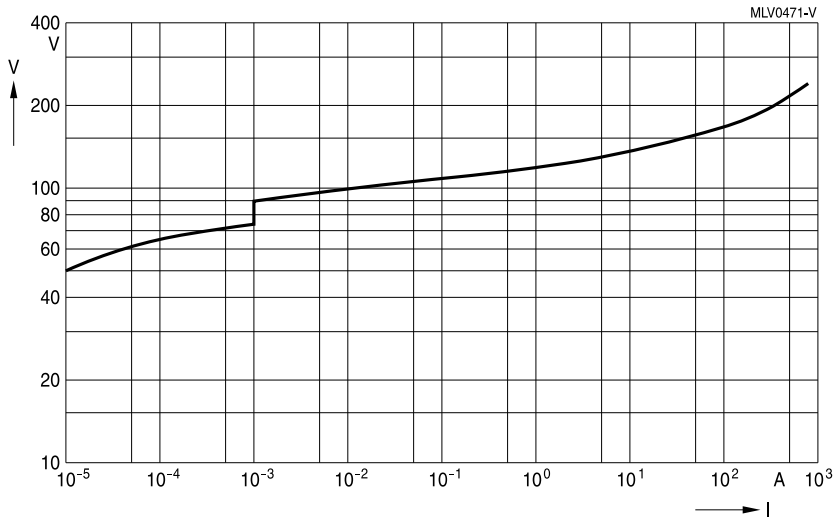
CT2220K40G

Multilayer varistors (MLVs)

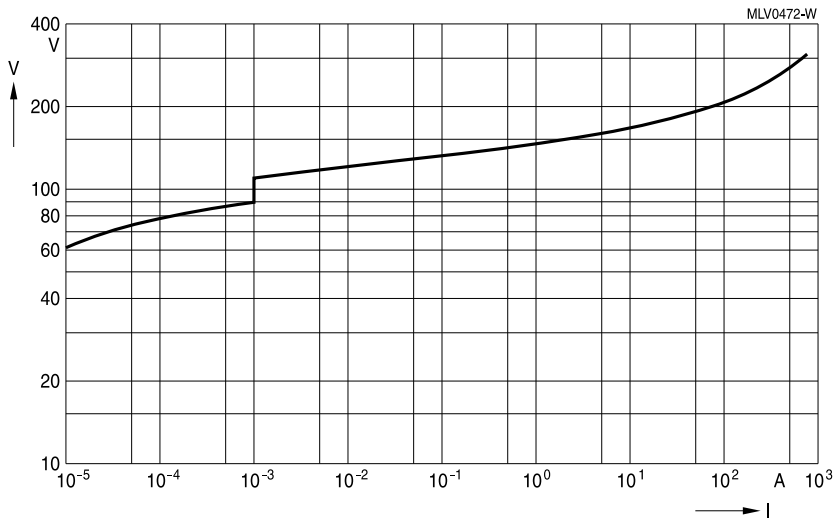
Surge protection series

SMD

V/I characteristics for surge protection types



CT2220K50G



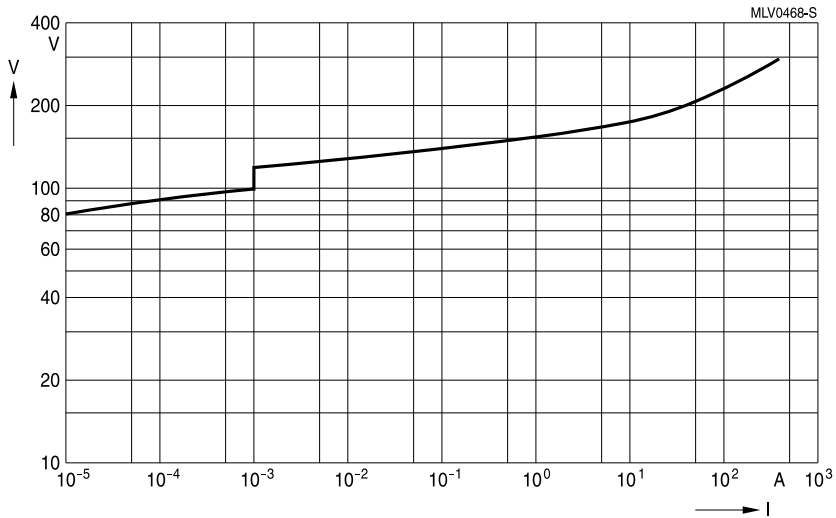
CT2220K60G

Multilayer varistors (MLVs)

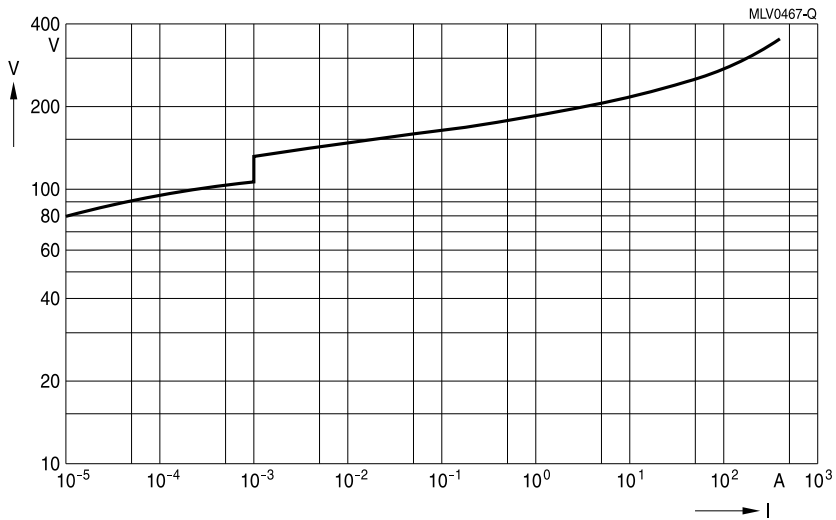
Surge protection series

SMD

V/I characteristics for telecom types



CT1812S60AG2



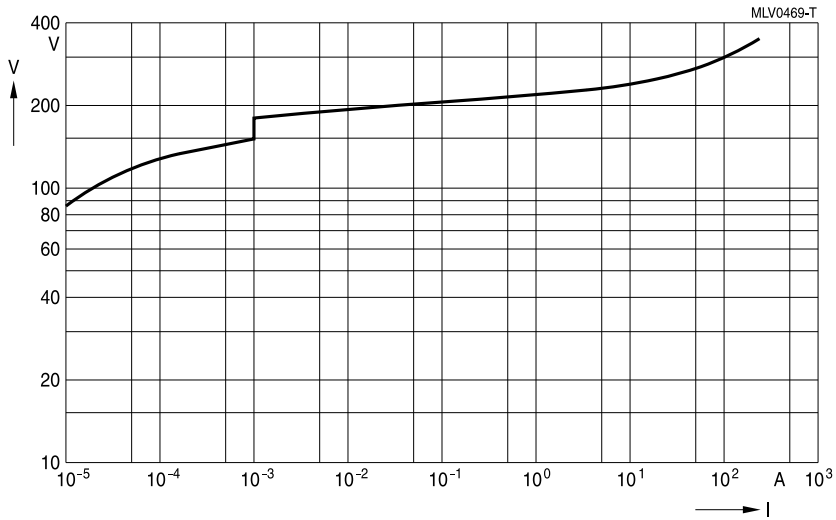
CT1812K75TELEG2

Multilayer varistors (MLVs)

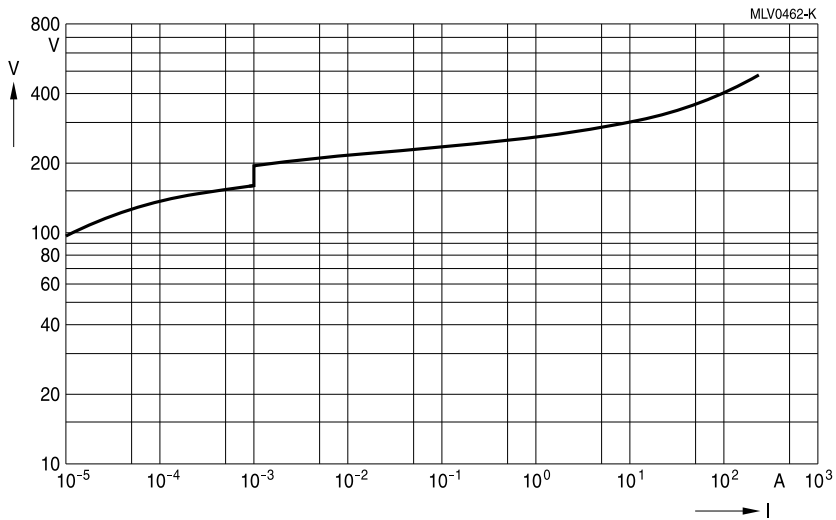
Surge protection series

SMD

V/I characteristics for telecom types



CT1812S95AG2



CT1812K115TELEG2

Multilayer varistors (MLVs)

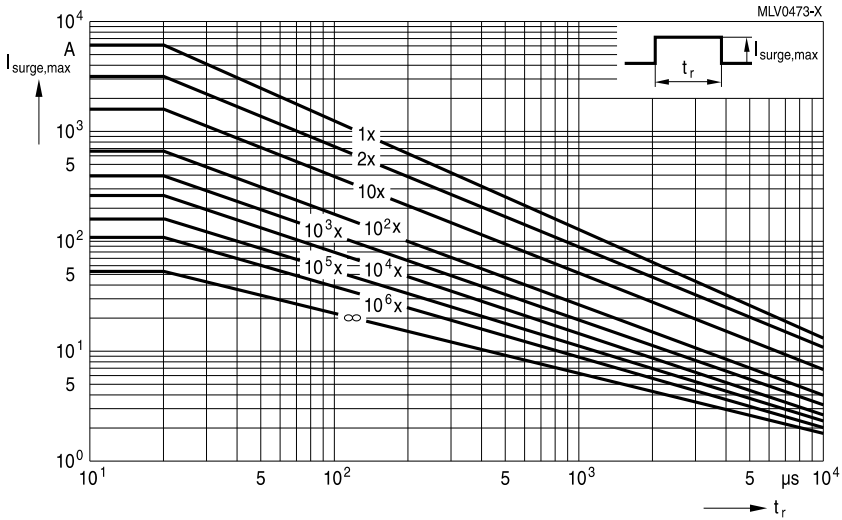
Surge protection series

SMD

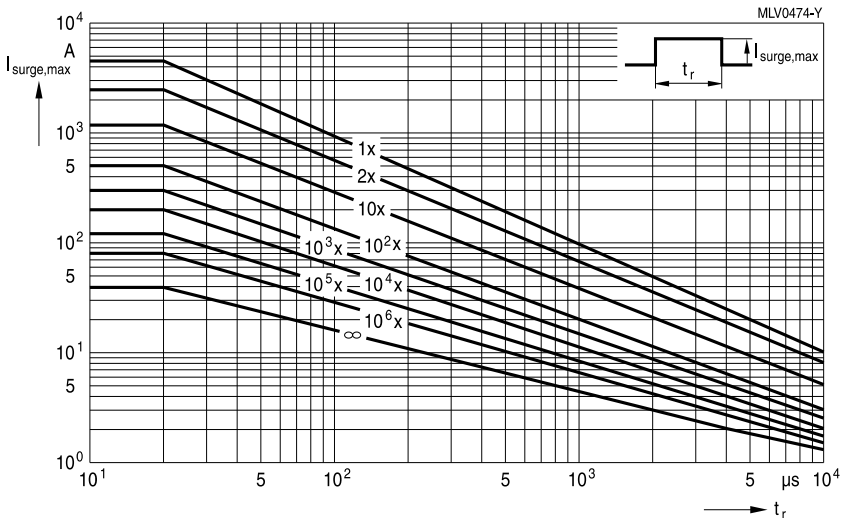
Derating curves for high surge protection types

Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CN2220K30E2GK2



CN2220K50E2GK2, CT2220K50E2G

Multilayer varistors (MLVs)

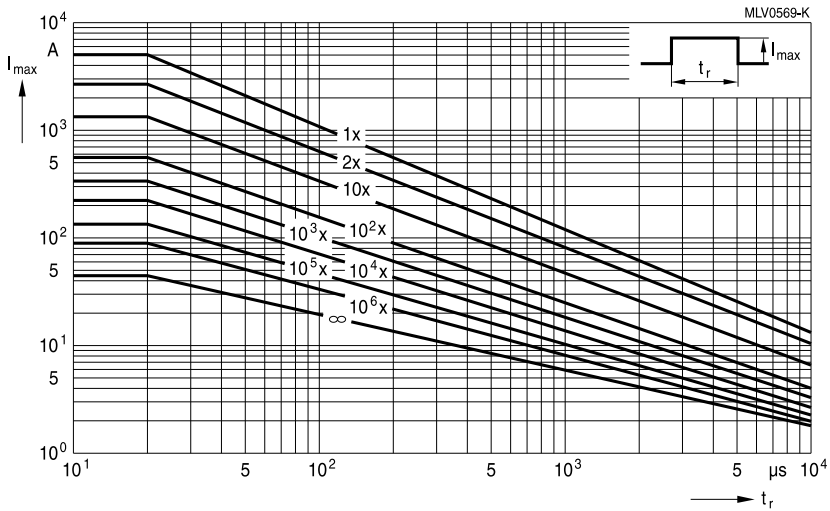
Surge protection series

SMD

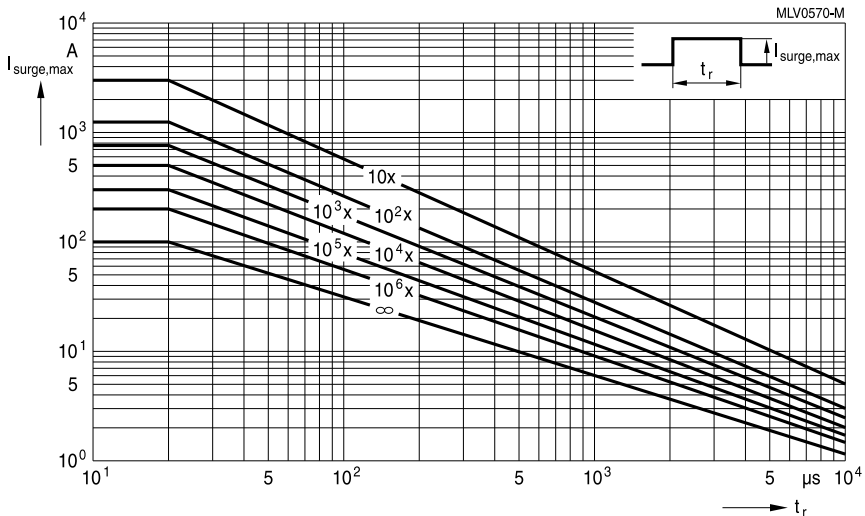
Derating curves for high surge protection types

Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT2220K30E2G



CT2220S50E3G

Multilayer varistors (MLVs)

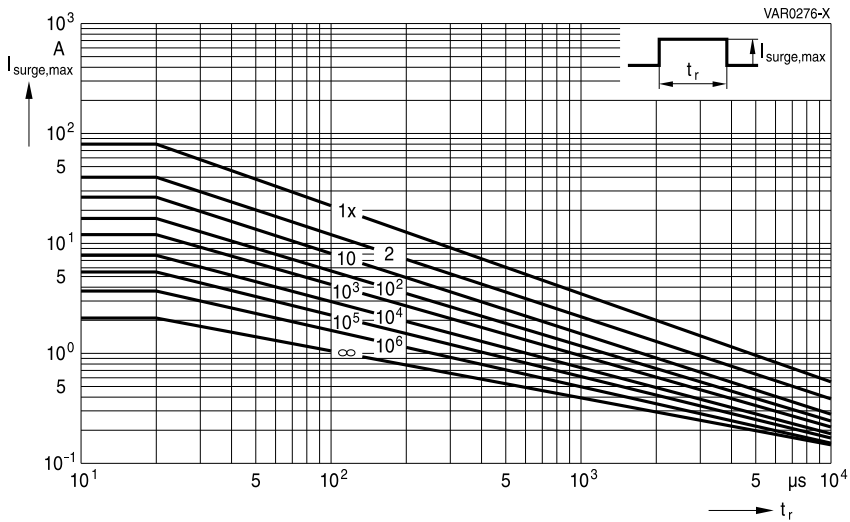
Surge protection series

SMD

Derating curves for surge protection types

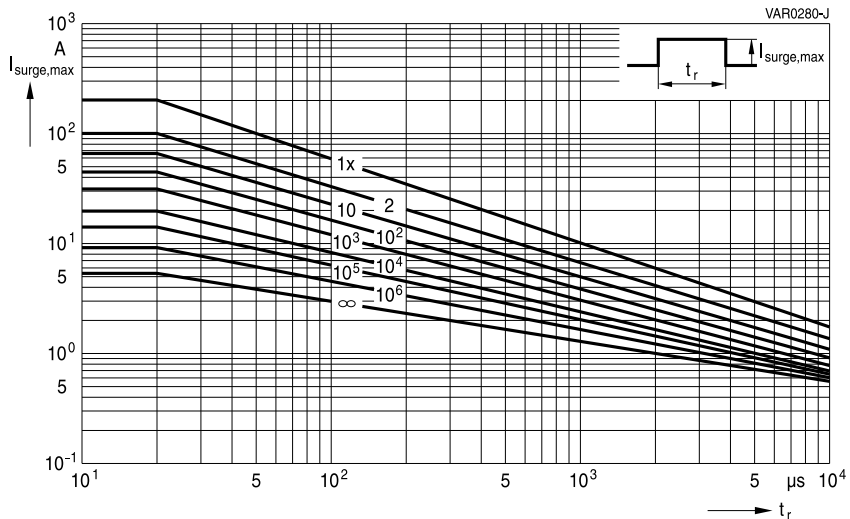
Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT0805K30G

CT0805K35G



CT1206K30G

CT1210K35G ... K60G

Multilayer varistors (MLVs)

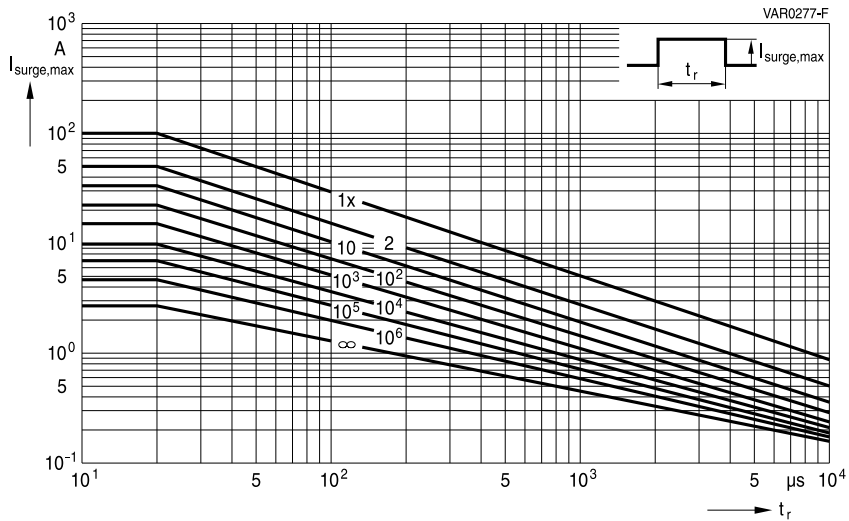
Surge protection series

SMD

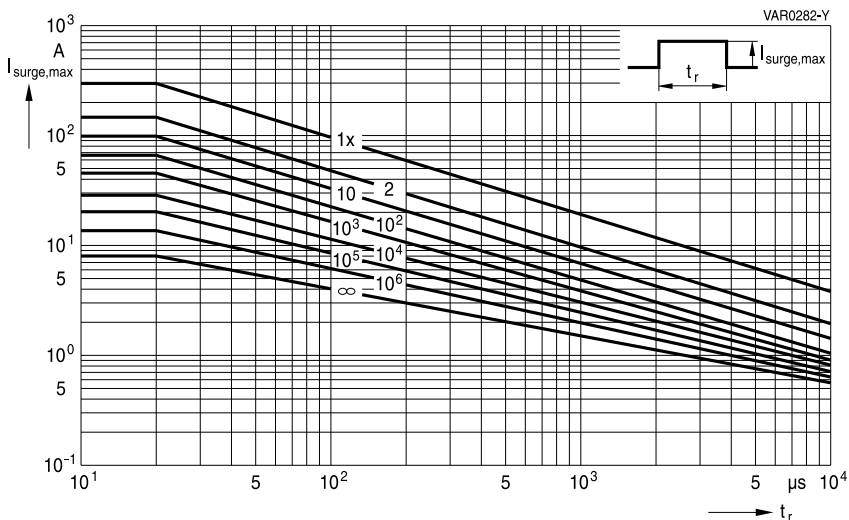
Derating curves for surge protection types

Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1206K35G ... K60G



CT1210K30G

Multilayer varistors (MLVs)

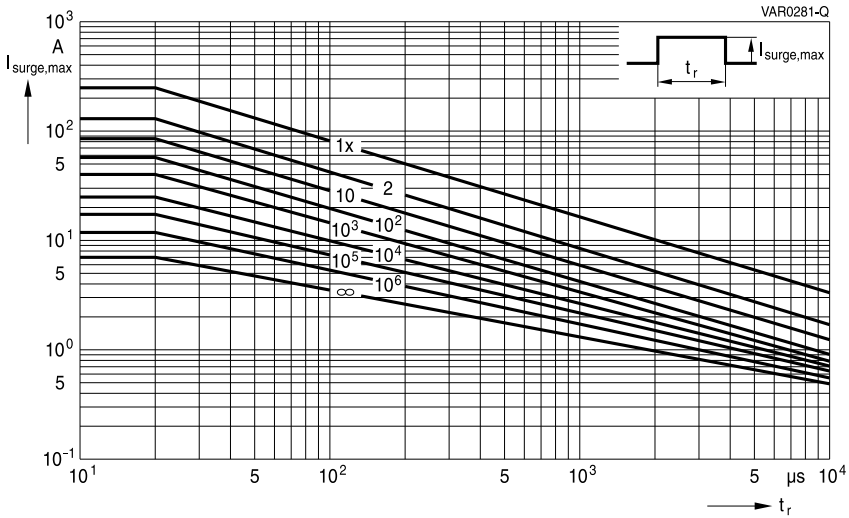
Surge protection series

SMD

Derating curves for surge protection types

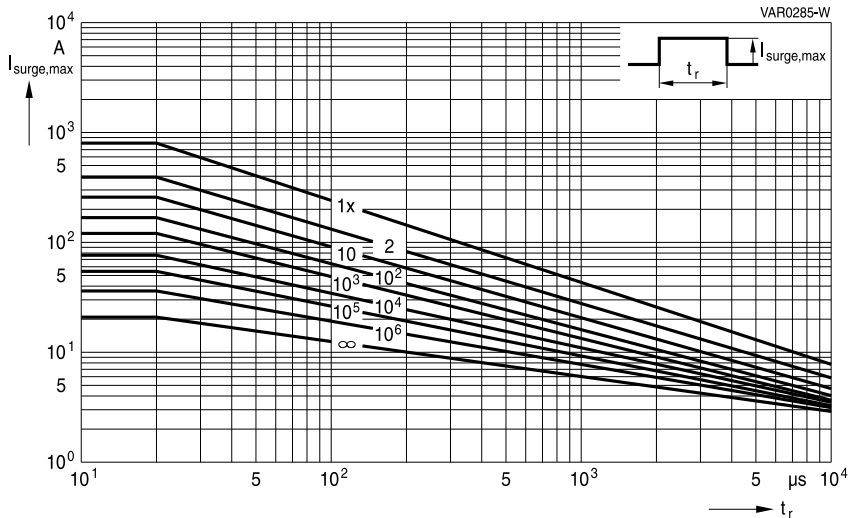
Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1210K40G

CT2220K30G



CT1812K30G

Multilayer varistors (MLVs)

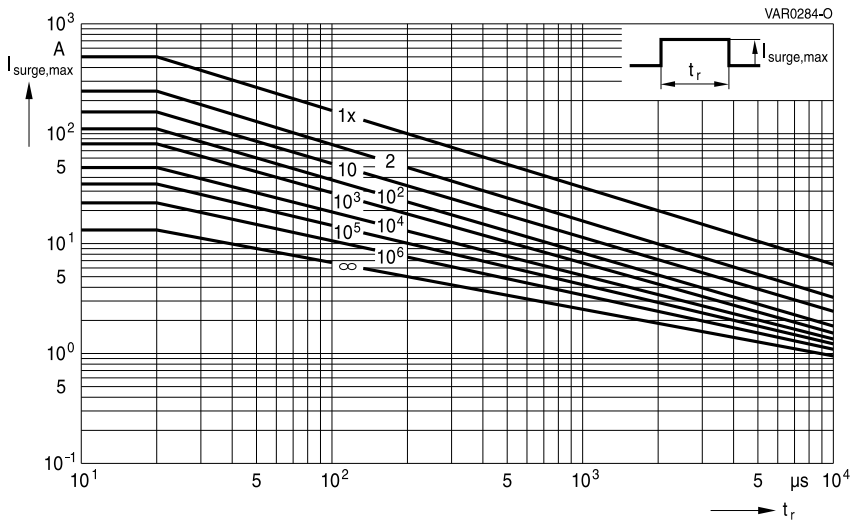
Surge protection series

SMD

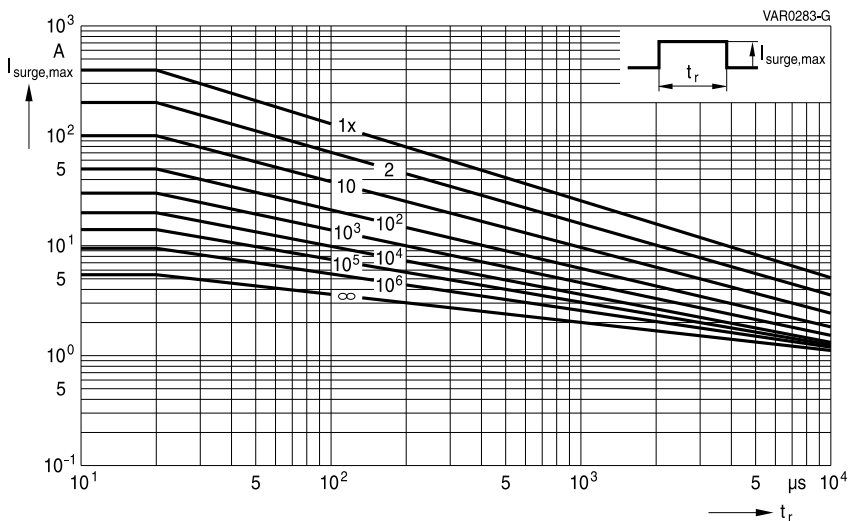
Derating curves for surge protection types

Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1812K35G ... K40G



CT1812K50G ... K60G

Multilayer varistors (MLVs)

Surge protection series

SMD

Derating curves for surge protection types

Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1812K130G2



CT2220K40G

Multilayer varistors (MLVs)

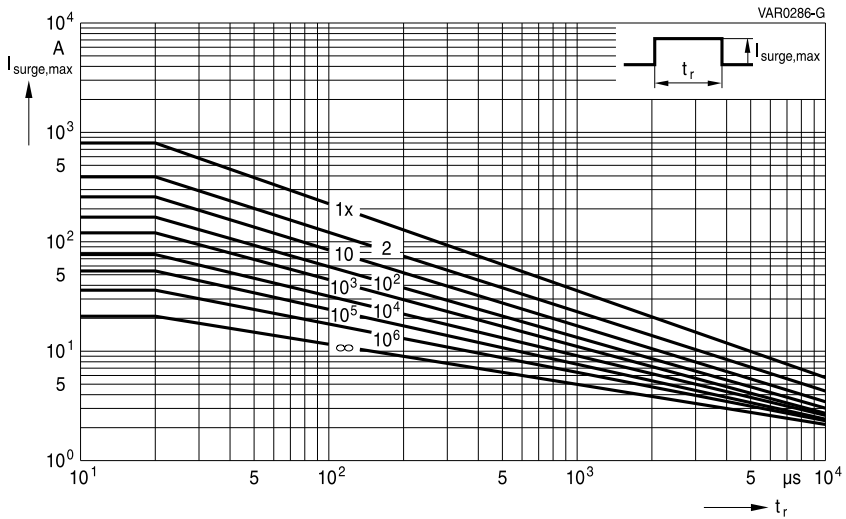
Surge protection series

SMD

Derating curves for surge protection types

Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT2220K50G ... K60G

Multilayer varistors (MLVs)

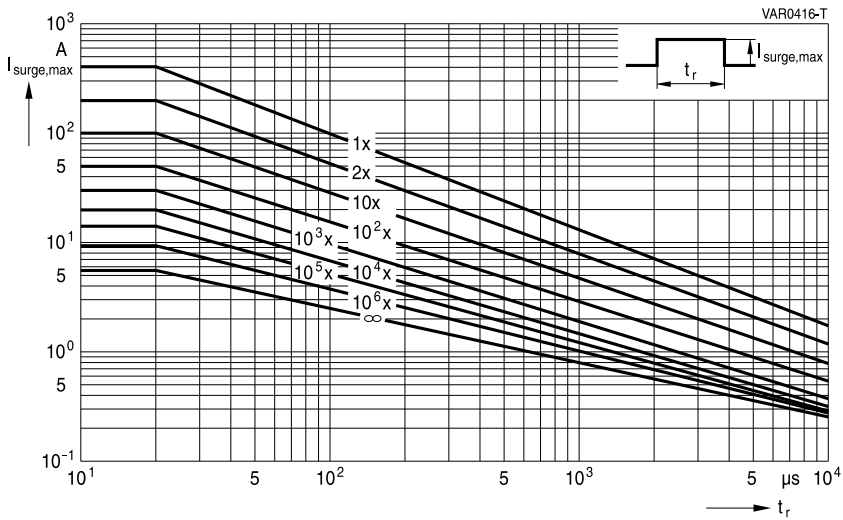
Surge protection series

SMD

Derating curves for telecom types

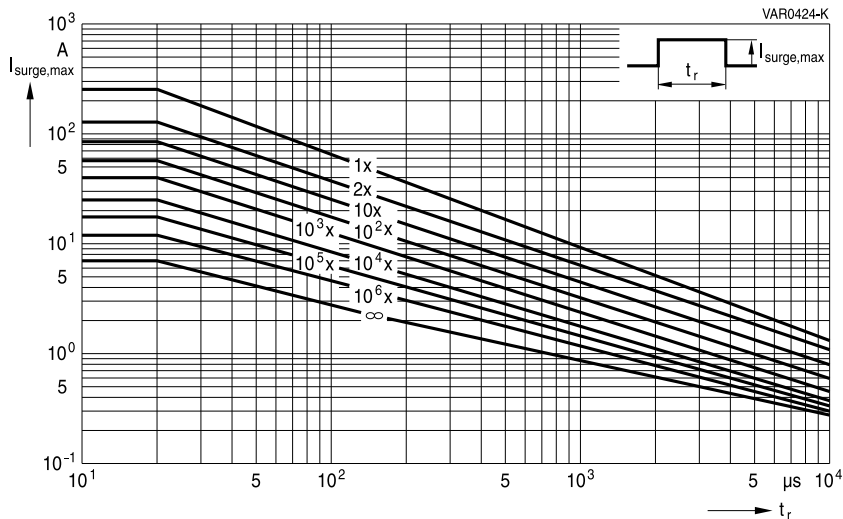
Maximum surge current $I_{\text{surge,max}} = f(t_r, \text{pulse train})$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1812S60AG2

CT1812K75TELEG2



CT1812S95AG2

CT1812K115TELEG2

Multilayer varistors (MLVs)

Surge protection series

SMD

Symbols and terms

For ceramic transient voltage suppressors (CTVS)

| Symbol | Term |
|-------------------|--|
| $C_{line,max}$ | Maximum capacitance per line |
| $C_{line,min}$ | Minimum capacitance per line |
| $C_{line,typ}$ | Typical capacitance per line |
| C_{max} | Maximum capacitance |
| C_{min} | Minimum capacitance |
| C_{nom} | Nominal capacitance |
| ΔC_{nom} | Tolerance of nominal capacitance |
| C_{typ} | Typical capacitance |
| $f_{cut-off,max}$ | Maximum cut-off frequency |
| $f_{cut-off,min}$ | Minimum cut-off frequency |
| $f_{cut-off,typ}$ | Typical cut-off frequency |
| $f_{res,typ}$ | Typical resonance frequency |
| I | Current |
| I_{clamp} | Clamping current |
| I_{leak} | Leakage current |
| $I_{leak,max}$ | Maximum leakage current |
| $I_{leak,typ}$ | Typical leakage current |
| I_{PP} | Peak pulse current |
| $I_{surge,max}$ | Maximum surge current (also termed peak current) |
| LCT | Lower category temperature |
| L_{typ} | Typical inductance |
| $P_{diss,max}$ | Maximum power dissipation |
| P_{PP} | Peak pulse power |
| R_{ins} | Insulation resistance |
| R_{min} | Minimum resistance |
| R_S | Resistance per line |
| $R_{S,typ}$ | Typical resistance per line |
| T_A | Ambient temperature |
| T_{op} | Operating temperature |
| $T_{op,max}$ | Maximum operating temperature |
| T_{stg} | Storage temperature |

Multilayer varistors (MLVs)
Surge protection series
SMD

| Symbol | Term |
|-------------------|--|
| t_r | Duration of equivalent rectangular wave |
| t_{resp} | Response time |
| $t_{resp,max}$ | Maximum response time |
| UCT | Upper category temperature |
| V | Voltage |
| $V_{BR,min}$ | Minimum breakdown voltage |
| $V_{clamp,max}$ | Maximum clamping voltage |
| $V_{DC,max}$ | Maximum DC operating voltage (also termed working voltage) |
| $V_{ESD,air}$ | Air discharge ESD capability |
| $V_{ESD,contact}$ | Contact discharge ESD capability |
| V_{jump} | Maximum jump-start voltage |
| $V_{RMS,max}$ | Maximum AC operating voltage, root-mean-square value |
| V_V | Varistor voltage (also termed breakdown voltage) |
| V_{LD} | Maximum load dump voltage |
| V_{leak} | Measurement voltage for leakage current |
| $V_{V,min}$ | Minimum varistor voltage |
| $V_{V,max}$ | Maximum varistor voltage |
| ΔV_V | Tolerance of varistor voltage |
| W_{LD} | Maximum load dump energy |
| W_{max} | Maximum energy absorption (also termed transient energy) |
| α_{typ} | Typical insertion loss |
| $\tan \delta$ | Dissipation factor |
| e | Lead spacing |
| $\ll * \gg$ | Maximum possible application conditions |

All dimensions are given in mm.

The commas used in numerical values denote decimal points.

Multilayer varistors (MLVs)
Surge protection series
SMD
For CeraDiodes

| CeraDiode | Semiconductor diode | |
|-------------------|-----------------------------------|---|
| C_{max} | | Maximum capacitance |
| C_{typ} | | Typical capacitance |
| I_{BR} | I_R, I_T | (Reverse) current @ breakdown voltage |
| I_{leak} | I_{RM} | (Reverse) leakage current |
| I_{PP} | I_P, I_{PP} | Current @ clamping voltage; peak pulse current |
| P_{PP} | P_{PP} | Peak pulse power |
| T_{op} | | Operating temperature |
| T_{stg} | | Storage temperature |
| V_{BR} | V_{BR} | (Reverse) breakdown voltage |
| $V_{BR,min}$ | | Minimum breakdown voltage |
| V_{clamp} | V_{cl}, V_C | Clamping voltage |
| $V_{clamp,max}$ | | Maximum clamping voltage |
| V_{DC} | $V_{RM}, V_{RWM}, V_{WM}, V_{DC}$ | (Reverse) stand-off voltage, working voltage, operating voltage |
| $V_{DC,max}$ | | Maximum DC operating voltage |
| $V_{ESD,air}$ | | Air discharge ESD capability |
| $V_{ESD,contact}$ | | Contact discharge ESD capability |
| V_{leak} | $V_{RM}, V_{RWM}, V_{WM}, V_{DC}$ | (Reverse) voltage @ leakage current |
| - *) | I_F | Current @ forward voltage |
| - *) | $I_{RM}, I_{RM,max}@V_{RM}$ | (Reverse) current @ maximum reverse stand-off voltage, working voltage, operating voltage |
| - *) | V_F | Forward voltage |

*) Not applicable due to bidirectional characteristics of CeraDiodes.

Multilayer varistors (MLVs)

Surge protection series

SMD

Cautions and warnings

General

Some parts of this publication contain statements about the suitability of our ceramic transient voltage suppressor (CTVS) components (multilayer varistors (MLVs)), CeraDiodes, ESD/EMI filters, leaded transient voltage/ RFI suppressors (SHCV types)) for certain areas of application, including recommendations about incorporation/design-in of these products into customer applications. The statements are based on our knowledge of typical requirements often made of our CTVS devices in the particular areas. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our CTVS components for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always incumbent on the customer to check and decide whether the CTVS devices with the properties described in the product specification are suitable for use in a particular customer application.

- Do not use EPCOS CTVS components for purposes not identified in our specifications, application notes and data books.
- Ensure the suitability of a CTVS in particular by testing it for reliability during design-in. Always evaluate a CTVS component under worst-case conditions.
- Pay special attention to the reliability of CTVS devices intended for use in safety-critical applications (e.g. medical equipment, automotive, spacecraft, nuclear power plant).

Design notes

- Always connect a CTVS in parallel with the electronic circuit to be protected.
- Consider maximum rated power dissipation if a CTVS has insufficient time to cool down between a number of pulses occurring within a specified isolated time period. Ensure that electrical characteristics do not degrade.
- Consider derating at higher operating temperatures. Choose the highest voltage class compatible with derating at higher temperatures.
- Surge currents beyond specified values will puncture a CTVS. In extreme cases a CTVS will burst.
- If steep surge current edges are to be expected, make sure your design is as low-inductance as possible.
- In some cases the malfunctioning of passive electronic components or failure before the end of their service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. In applications requiring a very high level of operational safety and especially when the malfunction or failure of a passive electronic component could endanger human life or health (e.g. in accident prevention, life-saving systems, or automotive battery line applications such as clamp 30), ensure by suitable design of the application or other measures (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of such a malfunction or failure. Only use CTVS components from the automotive series in safety-relevant applications.

Multilayer varistors (MLVs)

Surge protection series

SMD

- Specified values only apply to CTVS components that have not been subject to prior electrical, mechanical or thermal damage. The use of CTVS devices in line-to-ground applications is therefore not advisable, and it is only allowed together with safety countermeasures like thermal fuses.

Storage

- Only store CTVS in their original packaging. Do not open the package prior to processing.
- Storage conditions in original packaging: temperature -25 to $+45^{\circ}\text{C}$, relative humidity $\leq 75\%$ annual average, maximum 95%, dew precipitation is inadmissible.
- Do not store CTVS devices where they are exposed to heat or direct sunlight. Otherwise the packaging material may be deformed or CTVS may stick together, causing problems during mounting.
- Avoid contamination of the CTVS surface during storage, handling and processing.
- Avoid storing CTVS devices in harmful environments where they are exposed to corrosive gases for example (SO_x , Cl).
- Use CTVS as soon as possible after opening factory seals such as polyvinyl-sealed packages.
- Solder CTVS components after shipment from EPCOS within the time specified:
 - CTVS with Ni barrier termination, 12 months
 - CTVS with AgPt termination, 6 months
 - SHCV, 24 months

Handling

- Do not drop CTVS components and allow them to be chipped.
- Do not touch CTVS with your bare hands - gloves are recommended.
- Avoid contamination of the CTVS surface during handling.
- Washing processes may damage the product due to the possible static or cyclic mechanical loads (e.g. ultrasonic cleaning). They may cause cracks to develop on the product and its parts, which might lead to reduced reliability or lifetime.

Mounting

- When CTVS devices are encapsulated with sealing material or overmolded with plastic material, electrical characteristics might be degraded and the life time reduced.
- Make sure an electrode is not scratched before, during or after the mounting process.
- Make sure contacts and housings used for assembly with CTVS components are clean before mounting.
- The surface temperature of an operating CTVS can be higher. Ensure that adjacent components are placed at a sufficient distance from a CTVS to allow proper cooling.
- Avoid contamination of the CTVS surface during processing.

Multilayer varistors (MLVs)

Surge protection series

SMD

Soldering

- Complete removal of flux is recommended to avoid surface contamination that can result in an instable and/or high leakage current.
- Use resin-type or non-activated flux.
- Bear in mind that insufficient preheating may cause ceramic cracks.
- Rapid cooling by dipping in solvent is not recommended, otherwise a component may crack.

Operation

- Use CTVS only within the specified operating temperature range.
- Use CTVS only within specified voltage and current ranges.
- Environmental conditions must not harm a CTVS. Only use them in normal atmospheric conditions. Reducing the atmosphere (e.g. hydrogen or nitrogen atmosphere) is prohibited.
- Prevent a CTVS from contacting liquids and solvents. Make sure that no water enters a CTVS (e.g. through plug terminals).
- Avoid dewing and condensation.
- EPCOS CTVS components are mainly designed for encased applications. Under all circumstances avoid exposure to:
 - direct sunlight
 - rain or condensation
 - steam, saline spray
 - corrosive gases
 - atmosphere with reduced oxygen content
- EPCOS CTVS devices are not suitable for switching applications or voltage stabilization where static power dissipation is required.

This listing does not claim to be complete, but merely reflects the experience of EPCOS AG.

Display of ordering codes for EPCOS products

The ordering code for one and the same EPCOS product can be represented differently in data sheets, data books, other publications, on the EPCOS website, or in order-related documents such as shipping notes, order confirmations and product labels. **The varying representations of the ordering codes are due to different processes employed and do not affect the specifications of the respective products.** Detailed information can be found on the Internet under www.epcos.com/orderingcodes

Important notes

The following applies to all products named in this publication:

1. Some parts of this publication contain **statements about the suitability of our products for certain areas of application**. These statements are based on our knowledge of typical requirements that are often placed on our products in the areas of application concerned. We nevertheless expressly point out **that such statements cannot be regarded as binding statements about the suitability of our products for a particular customer application**. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always ultimately incumbent on the customer to check and decide whether an EPCOS product with the properties described in the product specification is suitable for use in a particular customer application.
2. We also point out that **in individual cases, a malfunction of electronic components or failure before the end of their usual service life cannot be completely ruled out in the current state of the art, even if they are operated as specified**. In customer applications requiring a very high level of operational safety and especially in customer applications in which the malfunction or failure of an electronic component could endanger human life or health (e.g. in accident prevention or lifesaving systems), it must therefore be ensured by means of suitable design of the customer application or other action taken by the customer (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of malfunction or failure of an electronic component.
3. **The warnings, cautions and product-specific notes must be observed.**
4. In order to satisfy certain technical requirements, **some of the products described in this publication may contain substances subject to restrictions in certain jurisdictions (e.g. because they are classed as hazardous)**. Useful information on this will be found in our Material Data Sheets on the Internet (www.epcos.com/material). Should you have any more detailed questions, please contact our sales offices.
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Important notes

7. The trade names EPCOS, Alu-X, CeraDiode, CeraLink, CeraPad, CeraPlas, CSMP, CSSP, CTVS, DeltaCap, DigiSiMic, DSSP, ExoCore, FilterCap, FormFit, LeaXield, MiniBlue, MiniCell, MKD, MKK, MotorCap, PCC, PhaseCap, PhaseCube, PhaseMod, PhiCap, PQSine, SIFERRIT, SIFI, SIKOREL, SilverCap, SIMDAD, SiMic, SIMID, SineFormer, SIOV, SIP5D, SIP5K, TFAP, ThermoFuse, WindCap are **trademarks registered or pending** in Europe and in other countries. Further information will be found on the Internet at www.epcos.com/trademarks.

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9